



VS-GB100TH120U Information

Heisener.com

VS-GB100TH120U Part Number

Manufacturer Vishay Semiconductor Diodes Division

Category Discrete Semiconductor Products

Transistors - IGBTs - Modules

Description IGBT 1200V 200A 1136W INT-A-PAK

Double INT-A-PAK (3 + 4)**Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









VS-GB100TH120U Specifications

Manufacturer Part Number	VS-GB100TH120U
Manufacturer	Vishay Semiconductor Diodes Division
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Modules
Package	Double INT-A-PAK (3 + 4)
Series	-
IGBT Type	NPT
Configuration	Half Bridge
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	200A
Power - Max	1136W
Vce(on) (Max) @ Vge, Ic	3.6V @ 15V, 100A
Current - Collector Cutoff (Max)	5mA
Input Capacitance (Cies) @ Vce	8.45nF @ 20V
Input	Standard
NTC Thermistor	No
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Package / Case	Double INT-A-PAK (3 + 4)
Supplier Device Package	Double INT-A-PAK
	Report errors?

VS-GB100TH120U Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

VS-GB100TH120U Payment Methods





















VS-GB100TH120U Shipping Methods













If you have any question about VS-GB100TH120U, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com